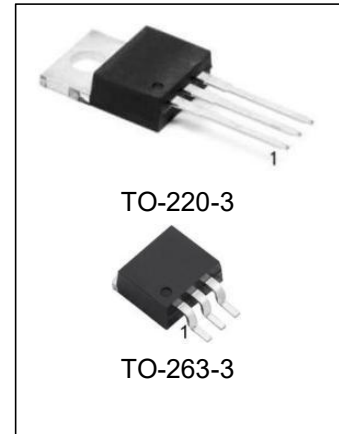


POSITIVE VOLTAGE REGULATORS

FEATURES

- OUTPUT CURRENT TO 1.5A
- OUTPUT VOLTAGES OF 5; 6; 8; 9; 10; 12; 15; 18; 24V
- THERMAL OVERLOAD PROTECTION
- SHORT CIRCUIT PROTECTION
- OUTPUT TRANSITION SOA PROTECTION



ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
LM7805CT	TO-220-3	LM7805C	TUBE	1000pcs/box
LM7806CT		LM7806C	TUBE	1000pcs/box
LM7808CT		LM7808C	TUBE	1000pcs/box
LM7809CT		LM7809C	TUBE	1000pcs/box
LM7810CT		LM7810C	TUBE	1000pcs/box
LM7812CT		LM7812C	TUBE	1000pcs/box
LM7815CT		LM7815C	TUBE	1000pcs/box
LM7818CT		LM7818C	TUBE	1000pcs/box
LM7824CT		LM7824C	TUBE	1000pcs/box
LM7805CS/TR	TO-263-3	LM7805C	REEL	500pcs/reel
LM7806CS/TR		LM7806C	REEL	500pcs/reel
LM7808CS/TR		LM7808C	REEL	500pcs/reel
LM7809CS/TR		LM7809C	REEL	500pcs/reel
LM7810CS/TR		LM7810C	REEL	500pcs/reel
LM7812CS/TR		LM7812C	REEL	500pcs/reel
LM7815CS/TR		LM7815C	REEL	500pcs/reel
LM7818CS/TR		LM7818C	REEL	500pcs/reel
LM7824CS/TR		LM7824C	REEL	500pcs/reel

DESCRIPTION

The LM78XX series of three-terminal positive regulators is available in TO-220 , TO263 packages and several fixed output voltages, making it useful in a wide range of applications.

These regulators can provide local on-card regulation, eliminating the distribution problems associated with single point regulation. Each type employs internal current limiting, thermal shut-down and safe area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 1A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltage and currents.

Schematic Diagram

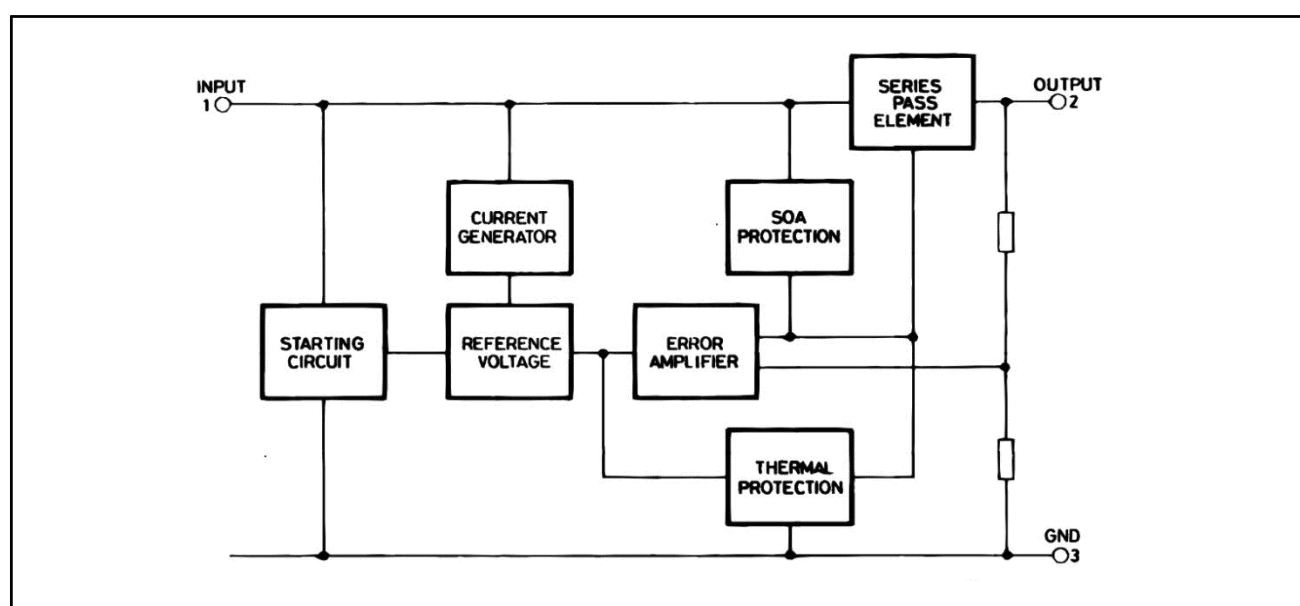


Figure 1: Schematic Diagram

Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_I	DC Input Voltage	35	V
I_O	Output Current	Internally Limited	
P_{tot}	Power Dissipation	Internally Limited	
T_{stg}	Storage Temperature Range	-65 to 150	°C
T_{LEAD}	Lead Temperature (Soldering, 10 seconds)	245	°C
T_{op}	Operating Junction Temperature Range	0 to 125	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Thermal Data

Symbol	Parameter	TO-220	TO-263	Unit
$R_{\theta JA}$	Junction-to-ambient thermal resistance	23.9	44.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	16.7	45.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	5.3	24.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	1.7	1.5	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	3.2	11.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	5.3	23.4	°C/W

Figure 2:Schematic Diagram

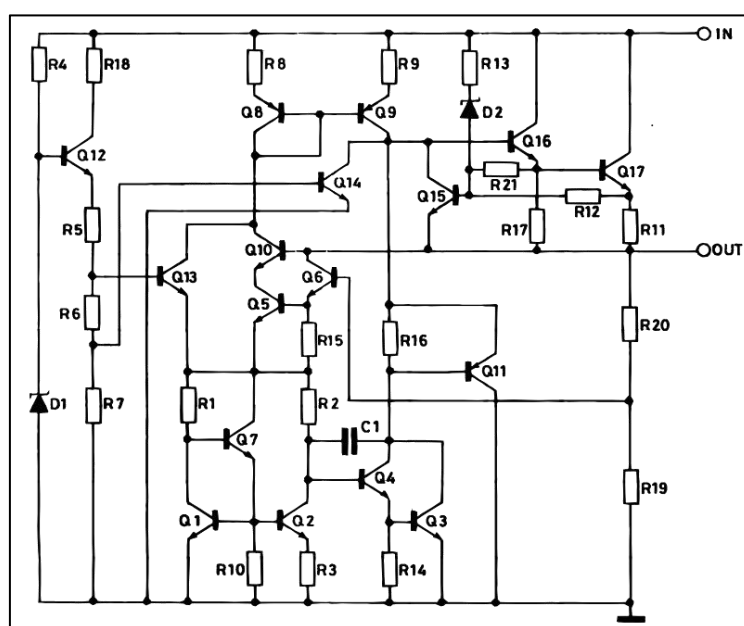
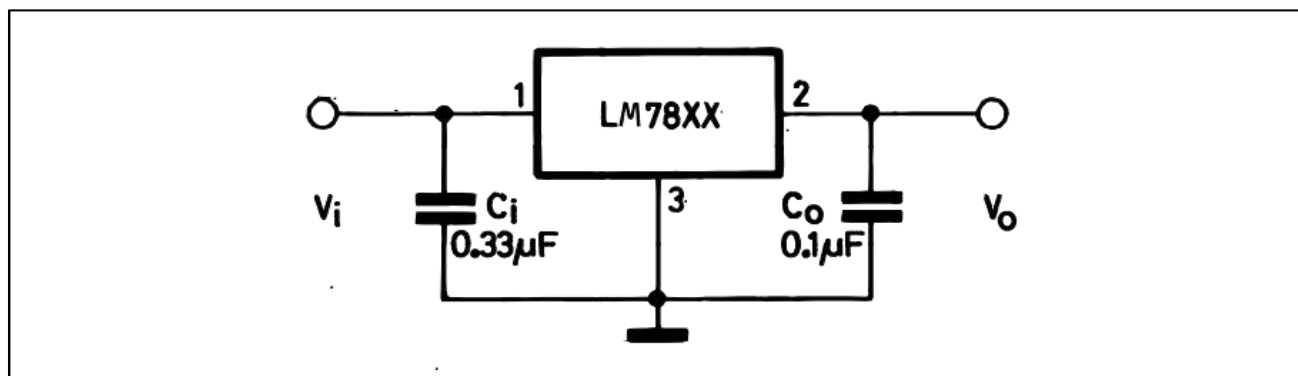


Figure 3: Application Circuits



TEST CIRCUITS

Figure 4: DC Parameter

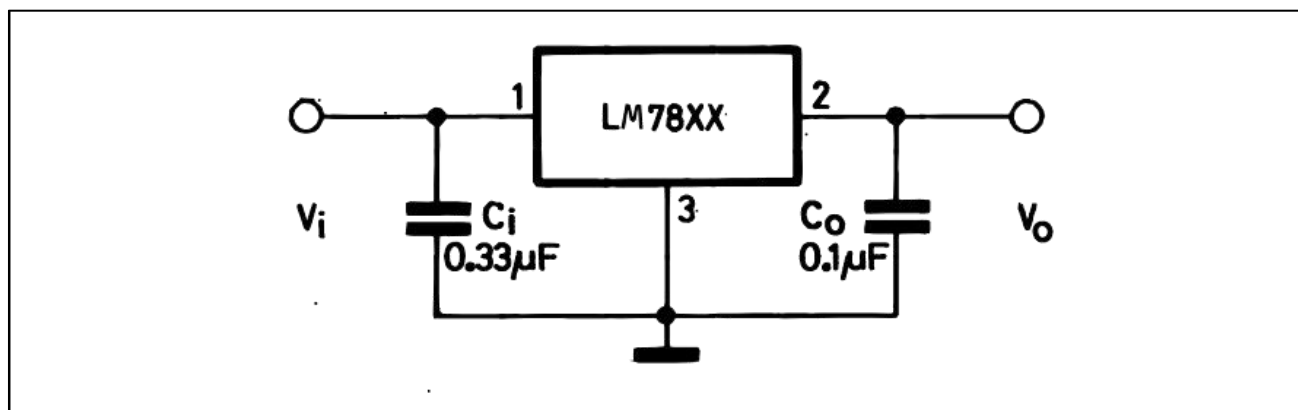


Figure 5: Load Regulation

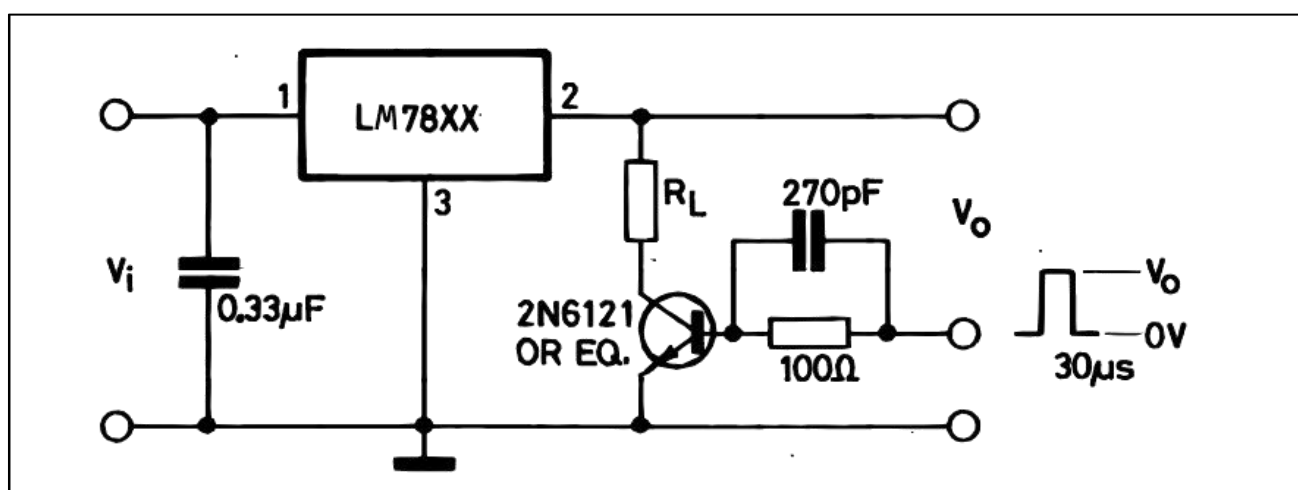
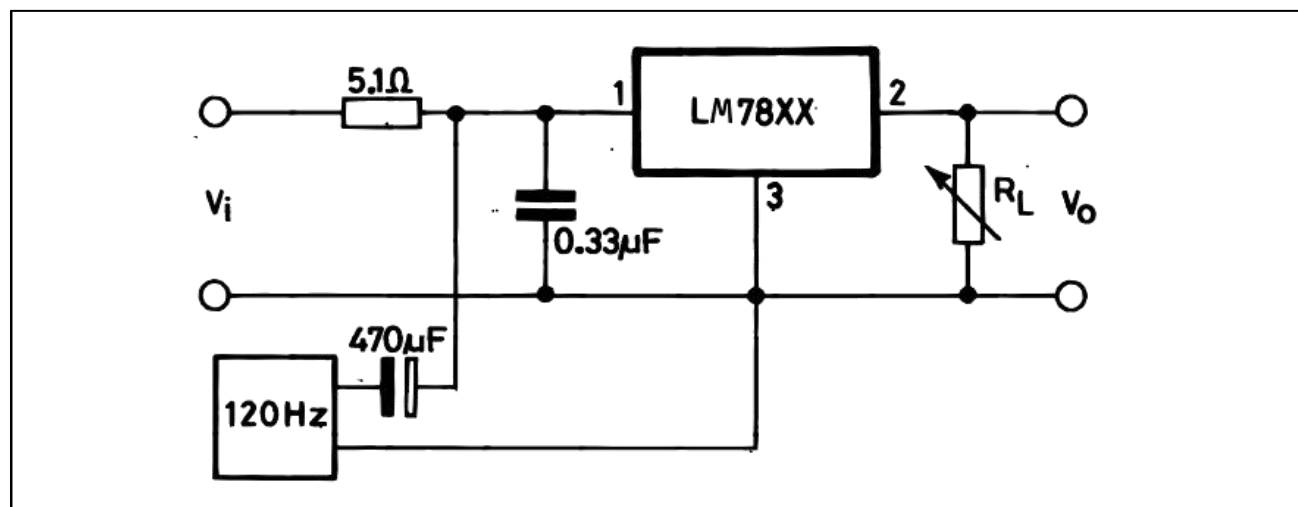


Figure 6:Ripple Rejection



Electrical Characteristics Of LM7805C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 10\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^\circ\text{C}$	4.8	5	5.2	V
V_O	Output Voltage	$I_O = 5\text{ mA to } 1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 7\text{ to } 20\text{ V}$	4.75	5	5.25	V
$\Delta V_O(*)$	Line Regulation	$V_I = 7\text{ to } 25\text{ V}$ $T_J = 25^\circ\text{C}$		3	100	mV
		$V_I = 8\text{ to } 12\text{ V}$ $T_J = 25^\circ\text{C}$		1	50	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to } 1.5\text{ A}$ $T_J = 25^\circ\text{C}$			100	mV
		$I_O = 250\text{ to } 750\text{ mA}$ $T_J = 25^\circ\text{C}$			50	
I_d	Quiescent Current	$T_J = 25^\circ\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to } 1\text{ A}$			0.5	mA
		$V_I = 7\text{ to } 25\text{ V}$			0.8	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-1.1		mV/ $^\circ\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to } 100\text{KHz}$ $T_J = 25^\circ\text{C}$		40		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 8\text{ to } 18\text{ V}$ $f = 120\text{Hz}$	62			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^\circ\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		17		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^\circ\text{C}$		0.75		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^\circ\text{C}$		2.2		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7806C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 11\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^{\circ}\text{C}$	5.75	6	6.25	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 8\text{ to }21\text{ V}$	5.7	6	6.3	V
$\Delta V_O(*)$	Line Regulation	$V_I = 8\text{ to }25\text{ V}$ $T_J = 25^{\circ}\text{C}$			120	mV
		$V_I = 9\text{ to }13\text{ V}$ $T_J = 25^{\circ}\text{C}$			60	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^{\circ}\text{C}$			120	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^{\circ}\text{C}$			60	
I_d	Quiescent Current	$T_J = 25^{\circ}\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 8\text{ to }25\text{ V}$			1.3	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-0.8		mV/ $^{\circ}\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^{\circ}\text{C}$		45		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 9\text{ to }19\text{ V}$ $f = 120\text{Hz}$	59			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^{\circ}\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		19		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^{\circ}\text{C}$		0.55		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^{\circ}\text{C}$		2.2		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7808C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 14\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^{\circ}\text{C}$	7.7	8	8.3	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 10.5\text{ to }25\text{ V}$	7.6	8	8.4	V
$\Delta V_O(*)$	Line Regulation	$V_I = 10.5\text{ to }25\text{ V}$ $T_J = 25^{\circ}\text{C}$			160	mV
		$V_I = 11\text{ to }17\text{ V}$ $T_J = 25^{\circ}\text{C}$			80	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^{\circ}\text{C}$			160	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^{\circ}\text{C}$			80	
I_d	Quiescent Current	$T_J = 25^{\circ}\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 10.5\text{ to }25\text{ V}$			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-0.8		mV/ $^{\circ}\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^{\circ}\text{C}$		52		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 11.5\text{ to }21.5\text{ V}$ $f = 120\text{Hz}$	56			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^{\circ}\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		16		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^{\circ}\text{C}$		0.45		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^{\circ}\text{C}$		2.2		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7809C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 15\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^\circ\text{C}$	8.64	9	9.36	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 11.5\text{ to }26\text{ V}$	8.55	9	9.45	V
$\Delta V_O(*)$	Line Regulation	$V_I = 11.5\text{ to }26\text{ V}$ $T_J = 25^\circ\text{C}$			180	mV
		$V_I = 12\text{ to }18\text{ V}$ $T_J = 25^\circ\text{C}$			90	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^\circ\text{C}$			180	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^\circ\text{C}$			90	
I_d	Quiescent Current	$T_J = 25^\circ\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 11.5\text{ to }26\text{ V}$			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-1		mV/ $^\circ\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^\circ\text{C}$		70		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 12\text{ to }23\text{ V}$ $f = 120\text{Hz}$	55			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^\circ\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		17		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^\circ\text{C}$		0.40		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^\circ\text{C}$		2.2		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7810C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 16\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^\circ\text{C}$	9.6	10	10.4	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 12.5\text{ to }26\text{ V}$	9.5	10	10.5	V
$\Delta V_O(*)$	Line Regulation	$V_I = 12.5\text{ to }26\text{ V}$ $T_J = 25^\circ\text{C}$			200	mV
		$V_I = 13.5\text{ to }19\text{ V}$ $T_J = 25^\circ\text{C}$			100	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^\circ\text{C}$			200	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^\circ\text{C}$			100	
I_d	Quiescent Current	$T_J = 25^\circ\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 12.5\text{ to }26\text{ V}$			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-1		mV/ $^\circ\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^\circ\text{C}$		70		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 13\text{ to }23\text{ V}$ $f = 120\text{Hz}$	55			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^\circ\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		17		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^\circ\text{C}$		0.40		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^\circ\text{C}$		2.2		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7812C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 19\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^\circ\text{C}$	11.5	12	12.5	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 14.5\text{ to }27\text{ V}$	11.4	12	12.6	V
$\Delta V_O(*)$	Line Regulation	$V_I = 14.5\text{ to }30\text{ V}$ $T_J = 25^\circ\text{C}$			240	mV
		$V_I = 16\text{ to }22\text{ V}$ $T_J = 25^\circ\text{C}$			120	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^\circ\text{C}$			240	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^\circ\text{C}$			120	
I_d	Quiescent Current	$T_J = 25^\circ\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 14.5\text{ to }30\text{ V}$			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-1		mV/ $^\circ\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^\circ\text{C}$		75		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 15\text{ to }25\text{ V}$ $f = 120\text{Hz}$	55			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^\circ\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		18		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^\circ\text{C}$		0.35		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^\circ\text{C}$		2.2		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7815C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 23\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^\circ\text{C}$	14.5	15	15.6	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 17.5\text{ to }30\text{ V}$	14.25	15	15.75	V
$\Delta V_O(*)$	Line Regulation	$V_I = 17.5\text{ to }30\text{ V}$ $T_J = 25^\circ\text{C}$			300	mV
		$V_I = 20\text{ to }26\text{ V}$ $T_J = 25^\circ\text{C}$			150	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^\circ\text{C}$			300	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^\circ\text{C}$			150	
I_d	Quiescent Current	$T_J = 25^\circ\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 17.5\text{ to }30\text{ V}$			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-1		mV/ $^\circ\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^\circ\text{C}$		90		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 18.5\text{ to }28.5\text{ V}$ $f = 120\text{Hz}$	54			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^\circ\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		19		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^\circ\text{C}$		0.23		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^\circ\text{C}$		2.2		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7818C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 26\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^\circ\text{C}$	17.3	18	18.7	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 21\text{ to }33\text{ V}$	17.1	18	18.9	V
$\Delta V_O(*)$	Line Regulation	$V_I = 21\text{ to }33\text{ V}$ $T_J = 25^\circ\text{C}$			360	mV
		$V_I = 24\text{ to }30\text{ V}$ $T_J = 25^\circ\text{C}$			180	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^\circ\text{C}$			360	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^\circ\text{C}$			180	
I_d	Quiescent Current	$T_J = 25^\circ\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 21\text{ to }33\text{ V}$			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-1		mV/ $^\circ\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^\circ\text{C}$		110		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 22\text{ to }32\text{ V}$ $f = 120\text{Hz}$	53			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^\circ\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		22		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^\circ\text{C}$		0.20		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^\circ\text{C}$		2.1		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics Of LM7824C

(refer to the test circuits, $T_J = 0$ to 125°C , $V_I = 33\text{V}$, $I_O = 500\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$ unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage	$T_J = 25^\circ\text{C}$	23	24	25	V
V_O	Output Voltage	$I_O = 5\text{ mA to }1\text{ A}$ $P_O \leq 15\text{W}$ $V_I = 27\text{ to }35\text{ V}$	22.8	24	25.2	V
$\Delta V_O(*)$	Line Regulation	$V_I = 27\text{ to }35\text{ V}$ $T_J = 25^\circ\text{C}$			480	mV
		$V_I = 30\text{ to }35\text{ V}$ $T_J = 25^\circ\text{C}$			240	
$\Delta V_O(*)$	Load Regulation	$I_O = 5\text{ mA to }1.5\text{ A}$ $T_J = 25^\circ\text{C}$			480	mV
		$I_O = 250\text{ to }750\text{ mA}$ $T_J = 25^\circ\text{C}$			240	
I_d	Quiescent Current	$T_J = 25^\circ\text{C}$			8	mA
ΔI_d	Quiescent Current Change	$I_O = 5\text{ mA to }1\text{ A}$			0.5	mA
		$V_I = 27\text{ to }35\text{ V}$			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5\text{ mA}$		-1.5		mV/ $^\circ\text{C}$
eN	Output Noise Voltage	$B = 10\text{Hz to }100\text{KHz}$ $T_J = 25^\circ\text{C}$		170		$\mu\text{V}/V_O$
SVR	Supply Voltage Rejection	$V_I = 28\text{ to }35\text{ V}$ $f = 120\text{Hz}$	50			dB
V_d	Dropout Voltage	$I_O = 1\text{ A}$ $T_J = 25^\circ\text{C}$		2		V
R_O	Output Resistance	$f = 1\text{ KHz}$		28		m Ω
I_{sc}	Short Circuit Current	$V_I = 35\text{ V}$ $T_J = 25^\circ\text{C}$		0.15		A
I_{scp}	Short Circuit Peak Current	$T_J = 25^\circ\text{C}$		2.1		A

(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Figure 7: Dropout Voltage vs Junction Temperature

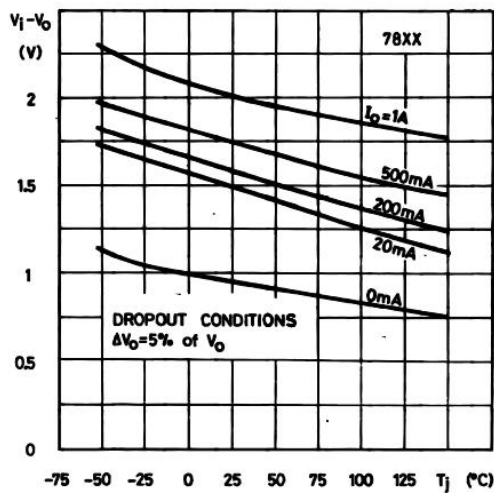


Figure 8: Peak Output Current vs Input/output Differential Voltage

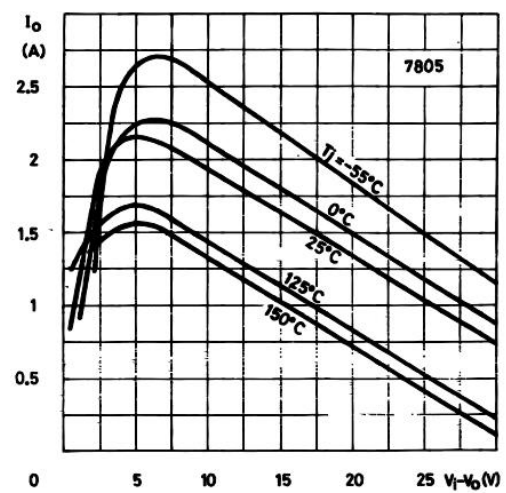


Figure 9: Supply Voltage Rejection vs Frequency

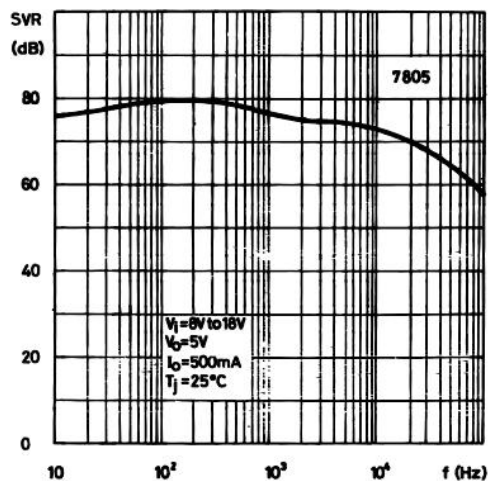


Figure 12: Quiescent Current vs Junction Temperature

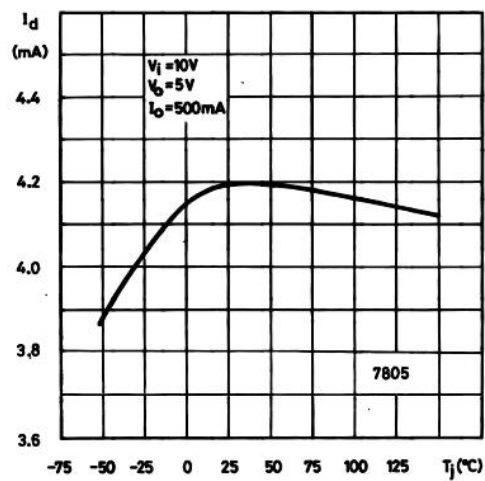


Figure 10: Output Voltage vs Junction Temperature

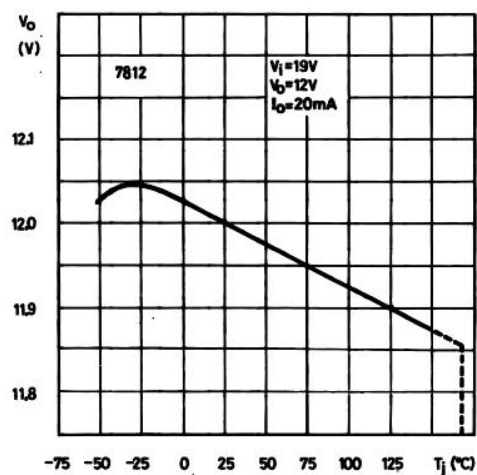


Figure 13: Load Transient Response

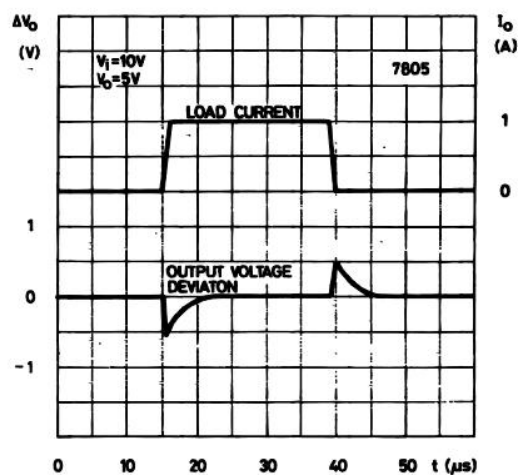


Figure 11: Output Impedance vs Frequency

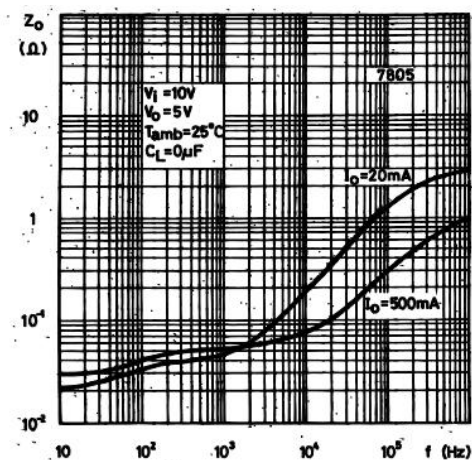


Figure 14: Line Transient Response

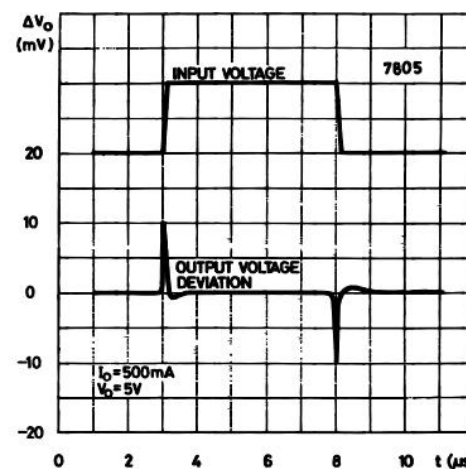


Figure 15: Quiescent Current vs Input Voltage

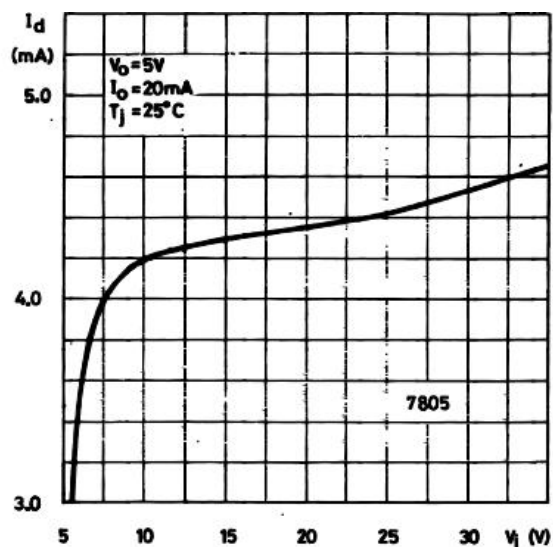
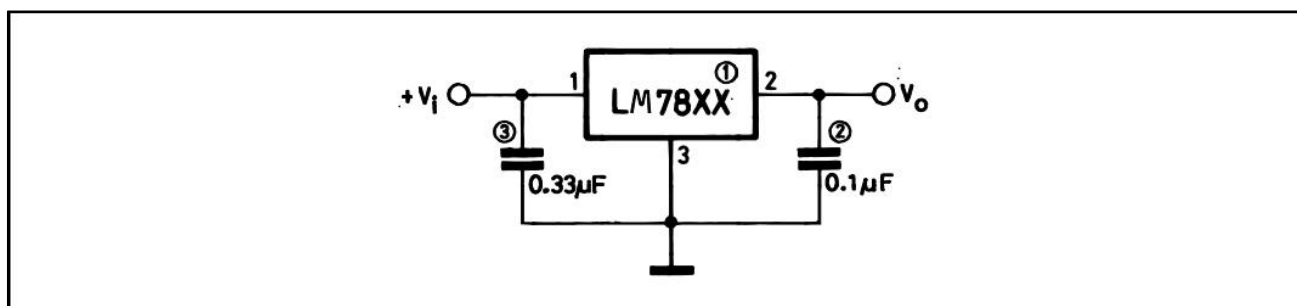


Figure 16: Fixed Output Regulator



NOTE:

1. To specify an output voltage, substitute voltage value for "XX".
2. Although no output capacitor is need for stability, it does improve transient response.
3. Required if regulator is locate an appreciable distance from power supply filter.

Figure 17: Current Regulator

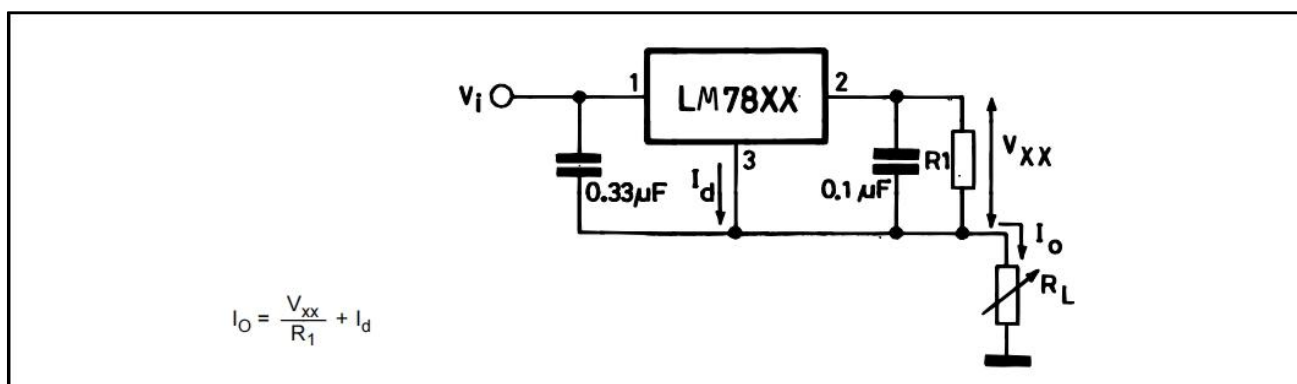


Figure 18: Circuit for Increasing Output Voltage

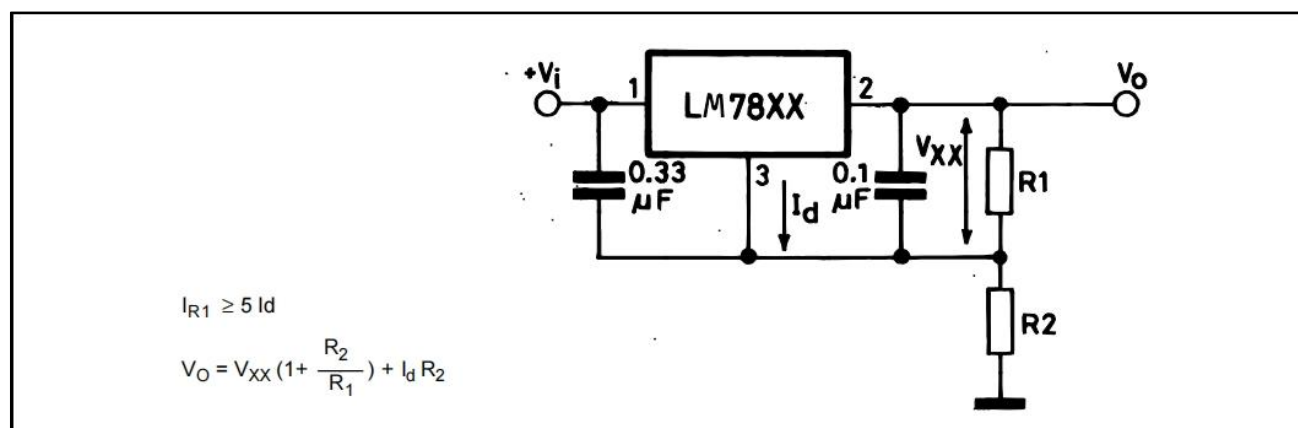


Figure 19: Adjustable Output Regulator (7 to 30V)

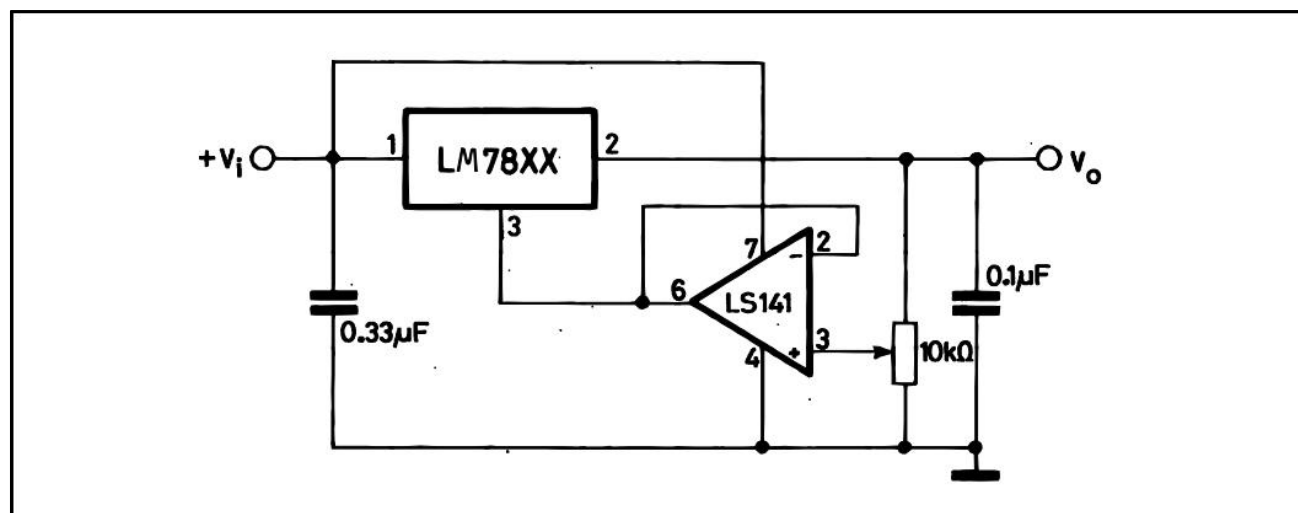
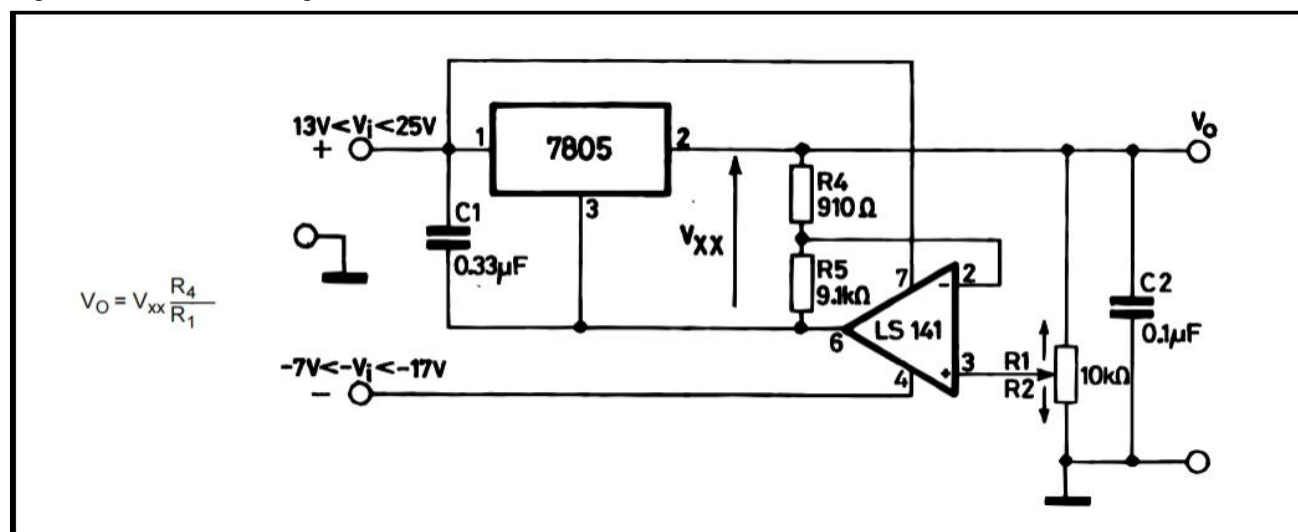
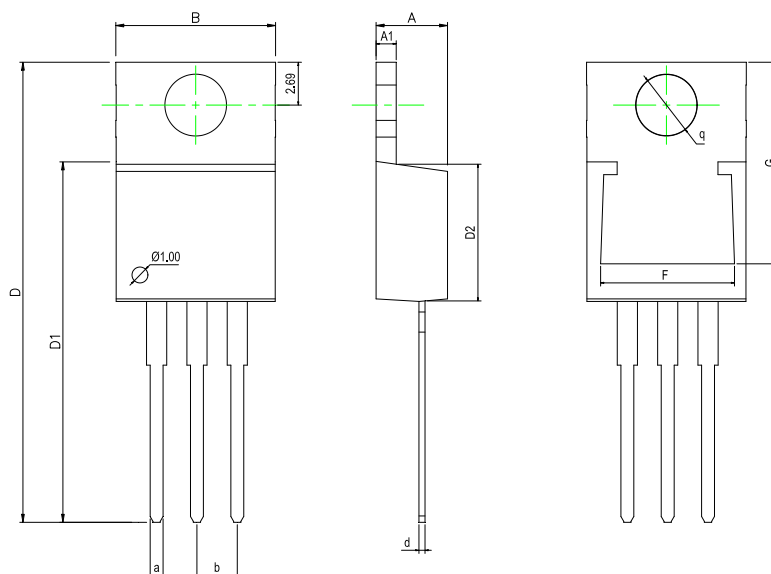


Figure 20: 0.5 to 10V Regulator



Physical Dimensions

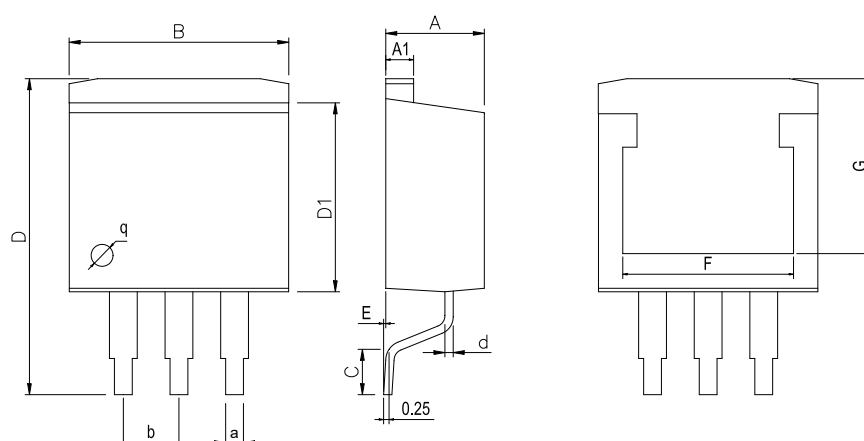
TO-220-3



Dimensions In Millimeters(TO-220-3)

Symbol:	A	A1	B	D	D1	D2	F	G	a	d	b	q
Min:	4.45	1.22	10	28.2	22.22	8.50	8.30	12.55	0.71	0.33	2.54	3.80
Max:	4.62	1.32	10.4	28.9	22.62	9.10	8.55	12.75	0.97	0.42	BSC	TYP

TO-263-3



Dimensions In Millimeters(TO-263-3)

Symbol:	A	A1	B	C	D	D1	E	F	G	a	b
Min:	4.45	1.22	10	1.89	14.1	8.38	0	7.20	7.20	0.71	2.54BSC
Max:	4.62	1.32	10.4	2.19	15.3	8.89	0.305	8.10	8.10	0.97	

Revision History

REVISION NUMBER	DATE	REVISION	PAGE
V1.0	2015-6	New	1-16
V1.1	2024-10	Updated Thermal Data	3
V1.2	2025-12	Update important statements、 Update TO263-3 Dimension drawing	14、 16

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